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LIST OF ART CITED BY APPLICANT (Use several sheets if necessary)				APPLICANT J. Dennis Keller et al.				
				FILING DATE July 17, 1998		GROUP 2823		
U.S. PATENT DOCUMENTS								
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	AA							
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							Yes No	
	AL							
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	AT							
EXAMINER <i>Michelle Estrada</i>				DATE CONSIDERED <i>1/12/05</i>				
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.								

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